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	Subclass	ISSUE CLASSIFICATION
	Class	

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PATENT NUMBER

U.S. UTILITY Patent Application

O.I.P.E. **PATENT DATE**
m.H. **BK③** **LA**
SCANNED **Q.A.**

APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART UNIT	EXAMINER
09/659456	F	372	43	287 81	A-173-2

ANTS
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semiconductor element in excited with GaN-based compound semiconductor laser element.

PTO-2040
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TERMINAL DISCLAIMER	DRAWINGS			CLAIMS ALLOWED	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
<input type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed.				NOTICE OF ALLOWANCE MAILED	
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S Patent. No. _____				ISSUE FEE	
				Amount Due	Date Paid
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